

SML60EUZ06B

Enhanced Ultrafast Recovery Diode 600 Volt, 60Amp

TECHNOLOGY

The planar passivated and enhanced ultrafast recovery diode features a triple charge control action utilising Semelab's Graded Buffer Zone technology combined with low emitter efficiency and local lifetime control techniques.

BENEFITS

- · Very fast recovery for low switching losses
- · Ultra soft recovery with low EMI generation
- High dynamic ruggedness under all conditions
- Low temperature dependency
- Low on-state losses with positive temperature coefficient
- Stable blocking voltage and low leakage current
- · Avalanche rated for high reliability circuit operation

Back of Case Cathode 1 - Cathode 2 - Anode 1 2

ackage outline for mechanical data and more details

TO-247 PACKAGE

Key Parameters

V_{R}	(max)	600V		
V_{F}	(typ)	2.1V		
I _F	(max)	60A		
t _{rr}	(max)	45ns		

APPLICATIONS

- Freewheeling Diode for IGBTs and MOSFETs
- Uninterruptible Power Supplies UPS
- Switch Mode Power Supplies SMPS
- · Inverse and Clamping Diode
- Snubber Diode
- · Fast Switching Rectification

ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C unless otherwise stated)

V_{RRM}	Peak Repetitive Reverse Voltage	600V
V_R	DC Reverse Blocking Voltage	600V
I _{FAV}	Average Forward Current @T _C = 85°C	60A
I _{FSM(surge)}	Repetitive Forward Current	150A
I _{FS(surge)}	Non-Repetitive Forward Current	600A
P_{D}	Power Dissipation @T _C = 85°C	130W
W_{AVL}	Avalanche Energy	40mJ
T_J , T_STG	Operating & Storage Junction Temperature	-55 to 150°C

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612. Document Number 2386

E-mail: sales@semelab.co.uk

Website: http://www.semelab.co.uk

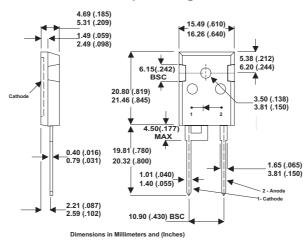


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ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

Parameter		Test Conditions		Min.	Тур.	Max.	Unit
STATIC	ELECTRICAL CHARACTERISTI	С					
V _F Forw		I _F = 60A	T _j = 25°C		2.1	2.5	V
	Forward Voltage Drop	I _F = 60A	T _j = 125°C		2.15		
		I _F = 30A	$T_j = 25^{\circ}C$		1.65		
I _R Lea	Lookogo Curront	V _R = 600V	$T_j = 25^{\circ}C$		1.2	400	μΑ
	Leakage Current	V _R = 600V	T _j = 125°C		0.75	5	mA
C _T	Junction Capacitance	V _R = 200V	$T_j = 25^{\circ}C$		82		pF
DYNAM	IC ELECTRICAL CHARACTERIS	STIC	•				
Q _{rr}	Reverse Recovery Charge	$-V_{R} = 300V$ $-d_{i} / d_{t} = 800A/\mu s$			0.88		μС
I _{rr}	Reverse Recovery Current				26		Α
t _{rr}	Reverse Recovery Time				68		nsec
Q _{rr}	Reverse Recovery Charge	$-V_{R} = 300V$ $-d_{i} / d_{t} = 800A/\mu s$	•		1.72		μС
I _{rr}	Reverse Recovery Current				39		Α
t _{rr}	Reverse Recovery Time				88		nsec
t _{rr}	Devene Deserver Time	V _R = 50V	I _F = 1A		45		nsec
	Reverse Recovery Time	$d_i / d_t = 100A/\mu s$	$T_J = 25^{\circ}C$				
THERM	AL AND MECHANICAL CHARAC	CTERISTICS					
$R_{\theta jc}$	Junction to Case Thermal Re	Junction to Case Thermal Resistance				0.6	°C/W
TL	Lead Temperature					300	°C
L _S	Stray Inductance				10		nH
Torque	Mounting Torque					1.1	N.m

TO-247 clip Package



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